

INFORMATION DISCLOSURE CITATION

Atty. Docket No.	4329.2309-02	Appln. No.	10/655,022
Applicant	Mizushima et al.		
Filing Date	September 5, 2003	Prior Group:	2812

U.S. PATENT DOCUMENTS

Examiner Initial*	Document Number	Issue Date	Name	Class	Sub Class	Filing Date If Appropriate
RD	2003/0001218A1	1/2/03	Takagi			
RD	6,326,658	12/4/01	Tsunashima et al.			
RD	6,319,782	11/2001	Nakabayashi			
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RD	5,124,276	6/1992	Samata et al.			
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FOREIGN PATENT DOCUMENTS

Document Number	Publication Date	Country	Class	Sub Class	Translation Yes or N
RD 4-372125	12/25/92	Japan			
RD 4-106980	4/8/92	Japan			

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Mieno et al., "Selective Doped Polysilicon Growth," Journal of the Electrochemical Society (November 1987), 134:2862-67

Examiner <i>Em Pompey</i>	Date Considered <i>12-13-03</i>
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	
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